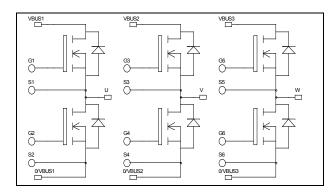


Triple phase leg Super Junction MOSFET Power Module



$$\begin{split} V_{DSS} &= 800V \\ R_{DSon} &= 150 m\Omega \ max \ @ \ Tj = 25^{\circ}C \\ I_D &= 28A \ @ \ Tc = 25^{\circ}C \end{split}$$

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- · COOLMOS
 - Ultra low R_{DSon}
 - Low Miller capacitance
 - Ultra low gate charge
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - Lead frames for power connections
- High level of integration



- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Very low (12mm) profile
- Each leg can be easily paralleled to achieve a phase leg of three times the current capability
- Module can be configured as a three phase bridge
- Module can be configured as a boost followed by a full bridge
- RoHS Compliant

Absolute	maximum	ratings

0/VBUS1

00

O/VBUS2

Symbol	l Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		800	V
T	Cantinuana David Comment	$T_c = 25$ °C	28	
I_D	Continuous Drain Current	$T_c = 80$ °C	21	A
I_{DM}	Pulsed Drain current		110	
V_{GS}	Gate - Source Voltage		±30	V
R_{DSon}	Drain - Source ON Resistance		150	mΩ
P_{D}	Maximum Power Dissipation $T_c = 25^{\circ}C$		277	W
I_{AR}	Avalanche current (repetitive and non repetitive)		17	A
E_{AR}	Repetitive Avalanche Energy		0.5	T
E_{AS}	Single Pulse Avalanche Energy		670	mJ

⊕ G5 © S5

0/VBUS3

TAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 800V$ $T_j = 25^{\circ}C$			50	μΑ
		$V_{GS} = 0V, V_{DS} = 800V$ $T_j = 125^{\circ}C$			375	
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 14A$			150	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 2mA$	2.1	3	3.9	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±150	nA

Dynamic Characteristics

•	Characteristic	Test Conditions	Min	Typ	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		4507		
C_{oss}	Output Capacitance	$V_{\rm DS} = 25V$		2092		pF
C_{rss}	Reverse Transfer Capacitance	f = 1MHz		108		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		180		
Q_{gs}	Gate – Source Charge	$V_{\text{Bus}} = 400V$		22		nC
Q_{gd}	Gate – Drain Charge	$I_D = 28A$		90		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @125°C		10		
$T_{\rm r}$	Rise Time	$V_{GS} = 15V$		13		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 533 \text{V}$ $I_{\text{D}} = 28 \text{A}$		83		ns
T_{f}	Fall Time	$R_G = 2.5\Omega$		35		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		486		т
E_{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 533V$ $I_D = 28A, R_G = 2.5\Omega$		278		μJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		850		т
E _{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 533V$ $I_D = 28A, R_G = 2.5\Omega$		342		μJ

Source - Drain diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{S}	Continuous Source current		$Tc = 25^{\circ}C$		28		٨
	(Body diode)		$Tc = 80^{\circ}C$		21		Α
V_{SD}	Diode Forward Voltage	$V_{GS} = 0V, I_S = -28A$	1			1.2	V
dv/dt	Peak Diode Recovery •					6	V/ns
t _{rr}	Reverse Recovery Time	$I_S = -28A$	$T_j = 25^{\circ}C$		550		ns
Q_{rr}	Reverse Recovery Charge	$V_R = 400V$ $di_S/dt = 200A/\mu s$	$T_j = 25^{\circ}C$		30		μС

• dv/dt numbers reflect the limitations of the circuit rather than the device itself.

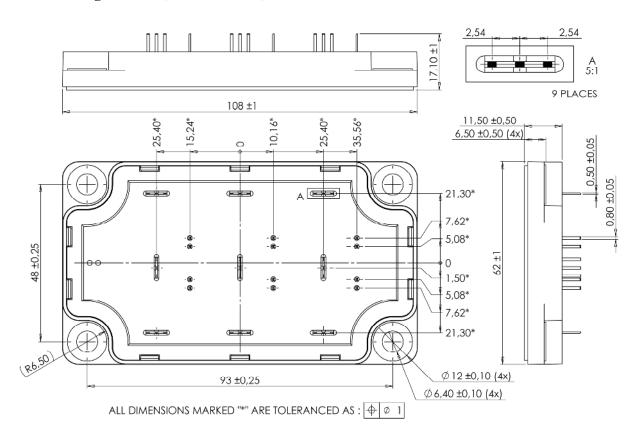
 $I_S \le$ - 28A $di/dt \le 200 A/\mu s$ $V_R \le V_{DSS}$ $T_j \le 150 ^{\circ} C$



Thermal and package characteristics

Symbol	Characteristic		Min	Тур	Max	Unit	
R_{thJC}	Junction to Case Thermal Resistance				0.45	°C/W	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz		4000			V	
T_{J}	Operating junction temperature range		-40		150		
T_{STG}	Storage Temperature Range		-40		125	°C	
$T_{\rm C}$	Operating Case Temperature		-40		100		
Torque	Mounting torque	To heatsink	M6	3		5	N.m
Wt	Package Weight					250	g

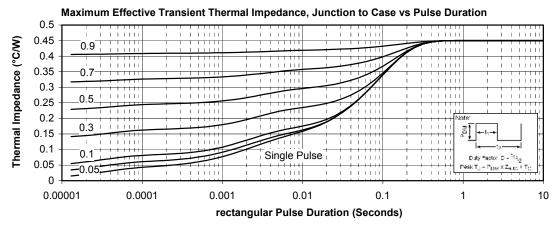
SP6-P Package outline (dimensions in mm)

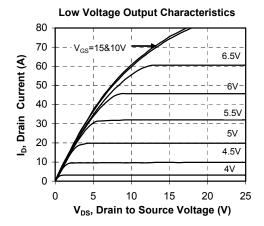


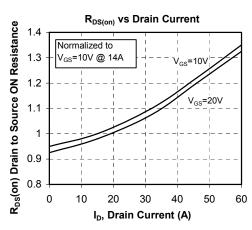
See application note 1902 - Mounting Instructions for SP6-P (12mm) Power Modules on www.microsemi.com

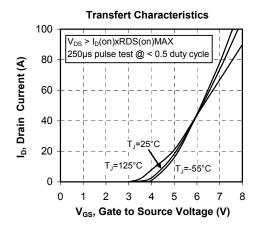


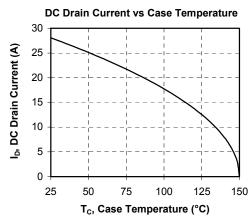
Typical Performance Curve



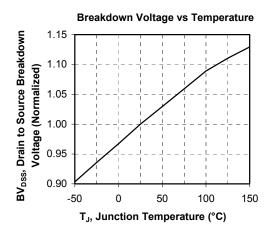


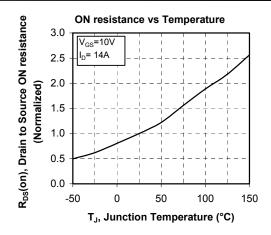


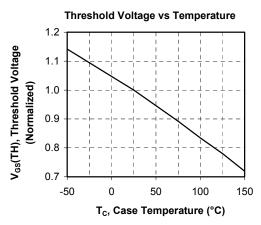


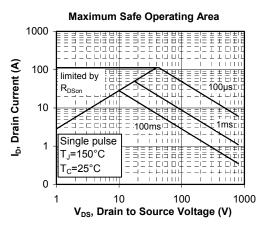


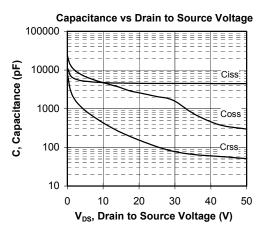


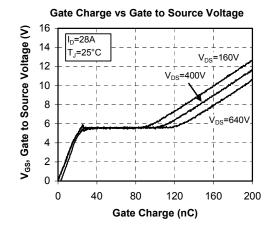






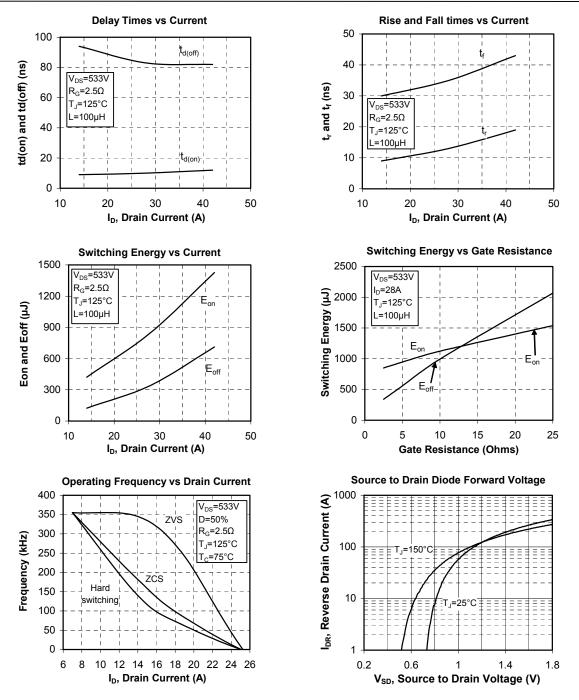






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